

United States Patent and Trademark Office



UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address: COMMISSIONER FOR PATENTS P.O. Box 1450 Alexandria, Virginia 22313-1450 www.uspto.gov

APPLICATION NO. FILING DATE		LING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.		
10/073,877 02/14/2002		2/14/2002	Takayuki Watanabe	020166	6745		
23850	7590	06/08/2004	EXAMINER				
		ATZ, QUINTOS,	GUERRERO, MARIA F				
1725 K STR	EET, NW						
SUITE 1000)		ART UNIT	PAPER NUMBER			
WASHING	ron, dc	20006	2822				
					T. 1 TT 3 () TT TT 0 () () () () ()		

DATE MAILED: 06/08/2004

Please find below and/or attached an Office communication concerning this application or proceeding.

				Application No.		Applicant(s)			
	Offic	Action Comment		10/073,87	7	WATANABE ET AL.			
Onic		Action Summary		Examiner		Art Unit			
				Maria Gue		2822			
Period fo	r Reply	ING DATE of this commun				•	idress		
THE N - Exten after: - If the - If NO - Failur Any n	MAILING Disions of time in SIX (6) MONTA period for reply period for reply to reply within eply received by	STATUTORY PERIOD F DATE OF THIS COMMUN hay be available under the provisions HS from the mailing date of this commy y specified above is less than thirty (3 y is specified above, the maximum sin the set or extended period for reply by the Office later than three months adjustment. See 37 CFR 1.704(b).	ICATION. s of 37 CFR 1.13 munication. 30) days, a reply tatutory period w v will, by statute,	36(a). In no ever within the statu vill apply and will cause the appli	nt, however, may a reply be to tory minimum of thirty (30) da expire SIX (6) MONTHS from cation to become ABANDON	imely filed ays will be considered timel the mailing date of this c ED (35 U.S.C. § 133).			
Status									
1)🛛	1)⊠ Responsive to communication(s) filed on <u>17 March 2004</u> .								
2a)⊠	This action	n is FINAL .	2b)∐ This	action is no	on-final.				
	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.								
Dispositi	on of Clai	ms							
5)□ 6)⊠ 7)⊠	Claim(s) 2-5,7-10,12 and 15-25 is/are pending in the application. 4a) Of the above claim(s) 7,8,12,15,16 and 23-26 is/are withdrawn from consideration. Claim(s) is/are allowed. Claim(s) 2 and 17-22 is/are rejected. Claim(s) 3-5,9 and 10 is/are objected to. Claim(s) are subject to restriction and/or election requirement.								
Application	on Papers	;							
9) 🗌 -	The specifi	cation is objected to by th	e Examiner	r.					
10)☐ The drawing(s) filed on is/are: a)☐ accepted or b)☐ objected to by the Examiner.									
	Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).								
	Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d). 11) The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.								
Priority u	nder 35 U	.S.C. § 119							
 12) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f). a) All b) Some * c) None of: Certified copies of the priority documents have been received. Certified copies of the priority documents have been received in Application No Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). * See the attached detailed Office action for a list of the certified copies not received. 									
Attachment									
		es Cited (PTO-892) rson's Patent Drawing Review (F	OTO 049\		4) Interview Summar Paper No(s)/Mail [
3) 🔲 Inform		sure Statement(s) (PTO-1449 or			5) Notice of Informal 6) Other:		O-152)		

DETAILED ACTION

1. This Office Action is in response to the Amendment filed November 21, 2003.

2. Claim 1, 6, 11, and 13-14 are canceled.

Claims 2-5, 7-10, 12, 15-25 are pending.

Priority

3. Receipt is acknowledged of papers submitted under 35 U.S.C. 119(a)-(d), which papers have been placed of record in the file.

Election/Restrictions

4. Applicant's election of Species I (claims 2-5, 9-10, 17-22) in Paper filed March 17, 2004 is acknowledged. Because applicant did not distinctly and specifically point out the supposed errors in the restriction requirement, the election has been treated as an election without traverse (MPEP § 818.03(a)).

Claims 7-8, 12, 15-16, 23-26 are withdrawn from further consideration pursuant to 37 CFR 1.142(b) as being drawn to a nonelected invention, there being no allowable generic or linking claim. Election was made **without** traverse in Paper filed March 17, 2004.

Art Unit: 2822

Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.
- 5. Claims 2 and 17-22 rejected under 35 U.S.C. 102(e) as being anticipated by Watanabe et al. (U.S. 2002/0119661 A1).

The applied reference has a common inventor with the instant application.

Based upon the earlier effective U.S. filing date of the reference, it constitutes prior art under 35 U.S.C. 102(e). This rejection under 35 U.S.C. 102(e) might be overcome either by a showing under 37 CFR 1.132 that any invention disclosed but not claimed in the reference was derived from the inventor of this application and is thus not the invention "by another," or by an appropriate showing under 37 CFR 1.131.

Watanabe et al. teaches forming a stacked structure of a first III-V compound semiconductor layer (102) (InGaAsP) containing In and having a composition different from InP and forming a second III-V compound semiconductor layer (InP)(103) containing In directly on the first III-V compound semiconductor layer (Fig. 17A, paragraphs 0176-0178). Watanabe et al. shows growing an InP layer (106) at regions adjacent the stacked structure to form a stepped structure of InP and the stacked structure together with the stepped structure defining a composite structure (Fig. 17C,

Art Unit: 2822

paragraph 0178). In addition, Watanabe et al. teaches wet-etching the composite structure using an etchant containing hydrochloric acid, acetic acid and water (Fig. 17D, paragraphs 0179-0180).

Furthermore, Watanabe et al. teaches obtaining a planar surface on a (100) plane and using water and hydrogen peroxide (paragraphs 0179-0180).

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

- (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 6. Claims 2, 17, and 19-22 are rejected under 35 U.S.C. 103(a) as being unpatentable over Otsuka et al. (U.S. 5,568,501) in view of Adachi et al. ("Chemical Etching of InGaAsP/Inp DH Wafer".

Otsuka et al. teaches forming a stacked structure of a first III-V compound semiconductor layer (2) (InGaAsP) containing In and having a composition different from InP and forming a second III-V compound semiconductor layer (20) (InGaAsP) containing In directly on the first III-V compound semiconductor layer (Fig. 1A-2A, 3A-3B, col. 6, lines 55-67, col. 7, lines 1-5, 30-40). Otsuka et al. shows growing an InP layer (6) at regions adjacent the stacked structure to form a stepped structure of InP (Fig. 2A, 3C, col. 7, lines 9-15, 30-35). In addition, Otsuka et al. teaches wet-etching

Art Unit: 2822

the second III-V compound semiconductor layer using an etchant containing acetic acid and thining the InP layer (6) (Fig. 2A, col. 7, lines 35-55).

Furthermore, Otsuka et al. shows using an etchant containing hydrochloric acid to adjust the stripe height (col. 7, lines 40-45). Otsuka et al. discloses removing the second III-V compound semiconductor layer using an etchant containing acetic acid (Fig. 3B-3C, col. 9, lines 40-47). Otsuka et al. teaches obtaining a planar surface on a (001) plane (Fig. 2A, 3C, col. 8, lines 30-33, col. 14, lines 35-45).

Otsuka et al. does not expressly teach wet-etching the composite structure using an etchant containing hydrochloric acid and acetic acid. However, Adachi et al. teaches using the etchant containing hydrochloric acid and acetic acid to etch an InP layer (Table 1, page 1054). Adachi et al. also teaches the etchant comprising water and or hydrogen peroxide (Table 1, page 1054).

Therefore, it would have been obvious to a person of ordinary skill in the art at the time of the invention to modify Otsuka et al. process by including the use of the etchant contain hydrochloric acid and acetic acid as taught by Adachi et al. in order to better control the etching process and to avoid overetching.

Allowable Subject Matter

7. Claims 3-5 and 9-10 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.

Response to Arguments

8. Applicant's arguments with respect to claims 2 and 17-22 have been considered but are moot in view of the new ground(s) of rejection.

Conclusion

9. The prior art made of record and not relied upon is considered pertinent to applicant's disclosure. Tsukiju et al. (U.S. 5,441,912) and Kimura et al. (U.S. 5,452,315) teach several steps related to applicant's disclosure.

Applicant's amendment necessitated the new ground(s) of rejection presented in this Office action. Accordingly, THIS ACTION IS MADE FINAL. See MPEP § 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the date of this final action.

Application/Control Number: 10/073,877 Page 7

Art Unit: 2822

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Maria Guerrero whose telephone number is 571-272-1837.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Amir Zarabian can be reached on 571-272-1852. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Maria Guerrero Primary Examiner May 28, 2004